

Vishay Semiconductors

Small Signal Schottky Diode



DESIGN SUPPORT TOOLS click logo to get started



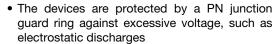
MECHANICAL DATA

Case: MiniMELF (SOD-80)
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/2.5K per 7" reel (8 mm tape), 12.5K/box

FEATURES

- For general purpose applications
- This diode features low turn-on voltage





HALOGEN FREE

- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

APPLICATIONS

· Applications where a very low forward voltage is required

PARTS TABLE			
PART	ORDERING CODE	CIRCUIT CONFIGURATION	REMARKS
BAS85-M	BAS85-M-18 or BAS85-M-08	Single	Tape and reel

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Continuous reverse voltage		V_R	30	V
Forward continuous current (1)		I _F	200	mA
Peak forward current (1)		I _{FM}	300	mA
Surge forward current (1)	t _p < 1 s	I _{FSM}	600	mA
Power dissipation (1)	T _{amb} = 65 °C	P _{tot}	200	mW

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature.

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	RAMETER TEST CONDITION SYMBOL VALUE			
Thermal resistance junction to ambient air (1)		R _{thJA}	430	K/W
Junction temperature		Tj	125	°C
Storage temperature range		T _{stq}	-55 to +150	°C

Note

(1) Valid provided that electrodes are kept at ambient temperature.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	$I_R = 10 \mu A \text{ (pulsed)}$	V _(BR)	30			V
Leakage current	V _R = 25 V	I_{R}		0.2	2	μΑ
	Pulse test $t_p < 300 \mu s$, $I_F = 0.1 \text{ mA}$	V_{F}			240	mV
	Pulse test $t_p < 300 \mu s$, $I_F = 1 mA$	V_{F}			320	mV
Forward voltage	Pulse test $t_p < 300 \mu s$, $I_F = 10 mA$	V_{F}			400	mV
	Pulse test $t_p < 300 \mu s$, $I_F = 30 \text{ mA}$	V_{F}		500		mV
	Pulse test $t_p < 300 \mu s$, $I_F = 100 \text{ mA}$	V_{F}			800	mV
Diode capacitance	$V_R = 1 V, f = 1 MHz$	C_D			10	pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA}, I_R = 1 \text{ mA}$	t _{rr}			5	ns

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

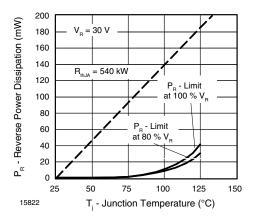


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

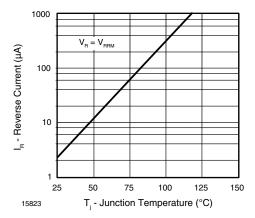


Fig. 2 - Reverse Current vs. Junction Temperature

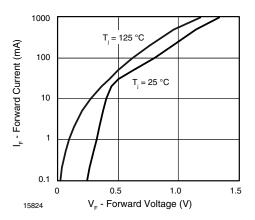


Fig. 3 - Forward Current vs. Forward Voltage

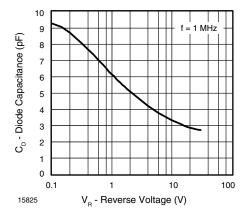
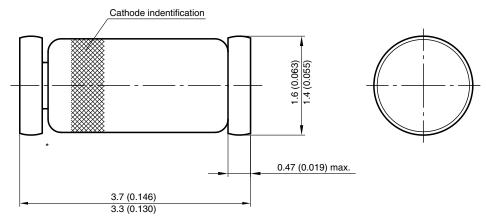


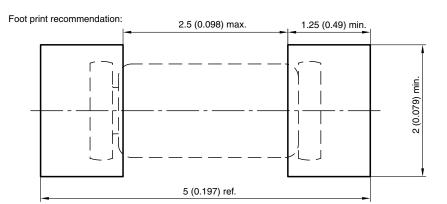
Fig. 4 - Diode Capacitance vs. Reverse Voltage

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PACKAGE DIMENSIONS in millimeters (inches): MiniMELF (SOD-80)



* The gap between plug and glass can be either on cathode or anode side



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